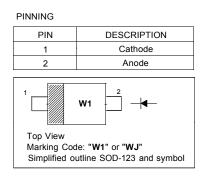


1N914W Silicon Epitaxial Planar Switching Diode



Absolute Maximum Ratings (T_a = 25 °C)

Parameter		Symbol	Value	Unit
Repetitive Reverse Voltage		V _{RRM}	100	V
Average Rectified Forward Current		I _{F(AV)}	200	mA
Non-repetitive Peak Forward Surge Current	att=1s att=1µs	I _{FSM}	1 2	А
Power Dissipation		P _{tot}	400	mW
Thermal Resistance from Junction to Ambient Air		$R_{ ext{ hetaJA}}$	312	°C/W
Junction Temperature		Tj	150	°C
Storage Temperature Range		T _{stg}	- 55 to + 150	°C

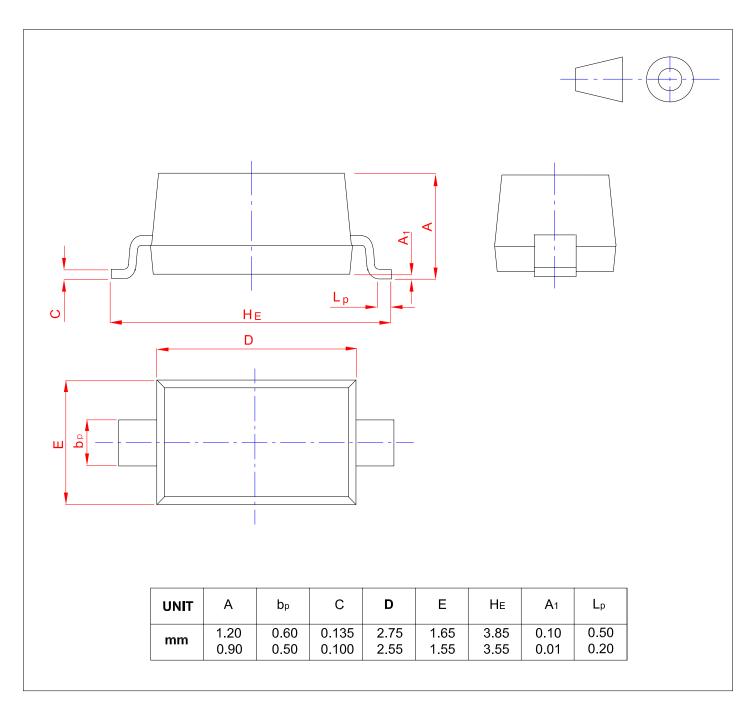
Electrical Characteristics (T_a = 25 °C)

Parameter	Symbol	Min.	Max.	Unit
Forward Voltage at I _F = 10 mA	V _F	-	1	V
Reverse Breakdown Voltage at $I_R = 5 \mu A$ at $I_R = 100 \mu A$	V _{(BR)R} V _{(BR)R}	75 100	-	V V
Reverse Current at $V_R = 20 V$ at $V_R = 75 V$ at $V_R = 20 V$, $T_j = 150 °C$	I _R	- - -	25 5 50	nA μA μA
Capacitance at V _R = 0 V, f = 1 MHz	C _{tot}	-	4	pF
Reverse Recovery Time at $I_F = I_R = 30$ mA, $I_{rr} = 3$ mA, $R_L = 100 \Omega$	t _{rr}	-	50	ns



PACKAGE OUTLINE

Plastic surface mounted package; 2 leads



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